NSN 5962-01-363-1122

Memory Microcircuit - Page 1 of 1



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## **Maximum Power Dissipation Rating:** 650.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Burn in and electrostatic sensitive and programmed **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 21 input **Case Outline Source And Designator:** D-9 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 7.0 volts power source Memory Device Type: **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 24 printed circuit

Shelf Life:

N/a

Pal

Unit Of Measure:

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## **Demilitarization:**

Yes - demil/mli

Fiig:

A458a0